

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|---|--------------------------------|------|
| Drain-Source Voltage | V _{DSS} | 100 | V |
| Gate-Source Voltage | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6), V _{GS} = 10V | Steady State T _A = +25°C T _A = +70°C | I _D 11.5 9.2 | A |
| | Steady State T _C = +25°C T _C = +100°C | I _D 29.5 18.6 | A |
| Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%) | I _{DM} | 75 | A |
| Maximum Continuous Body Diode Forward Current (Note 6) | I _S | 3 | A |
| Avalanche Current (Note 8), L=0.3mH | I _{AS} | 10 | A |
| Avalanche Energy (Note 8), L=0.3mH | E _{AS} | 15 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|---|-------------|------|
| Total Power (Note 5) | P _D | 1.4 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State t < 10s R _{θJA} | 90 | °C/W |
| | | 48.8 | |
| Total Power Dissipation (Note 6) | P _D | 1.9 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State t < 10s R _{θJA} | 66 | °C/W |
| | | 35.8 | |
| Thermal Resistance, Junction to Case (Note 6) | R _{θJC} | 10.1 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|-----|------|------|------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 100 | — | — | V | V _{GS} = 0V, I _D = 1mA |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | 1 | μA | V _{DS} = 80V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | — | — | ±100 | nA | V _{GS} = ±20V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.4 | 1.9 | 2.8 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 8 | 9.5 | mΩ | V _{GS} = 10V, I _D = 13A |
| | | — | 9 | 12 | | V _{GS} = 6V, I _D = 13A |
| | | — | 10 | 14.5 | | V _{GS} = 4.5V, I _D = 5A |
| Diode Forward Voltage | V _{SD} | — | 0.8 | 1.3 | V | V _{GS} = 0V, I _S = 13A |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | — | 2592 | — | pF | V _{DS} = 50V, V _{GS} = 0V f = 1MHz |
| Output Capacitance | C _{oss} | — | 792 | — | | |
| Reverse Transfer Capacitance | C _{rss} | — | 45 | — | | |
| Gate Resistance | R _g | — | 2 | — | Ω | V _{DS} = 0V, V _{GS} = 0V, f = 1MHz |
| Total Gate Charge | Q _g | — | 53.7 | — | nC | V _{DD} = 50V, I _D = 13A, V _{GS} = 10V |
| Gate-Source Charge | Q _{gs} | — | 10.6 | — | | |
| Gate-Drain Charge | Q _{gd} | — | 8.2 | — | | |
| Turn-On Delay Time | t _{D(ON)} | — | 11.6 | — | ns | V _{DD} = 50V, V _{GS} = 10V, I _D = 13A, R _g = 6Ω |
| Turn-On Rise Time | t _r | — | 14.1 | — | | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 42.9 | — | | |
| Turn-Off Fall Time | t _f | — | 22 | — | | |
| Reverse Recovery Time | t _{RR} | — | 49.8 | — | ns | I _F = 13A, di/dt = 100A/μs |
| Reverse Recovery Charge | Q _{RR} | — | 85.1 | — | nC | |

- Notes:
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.

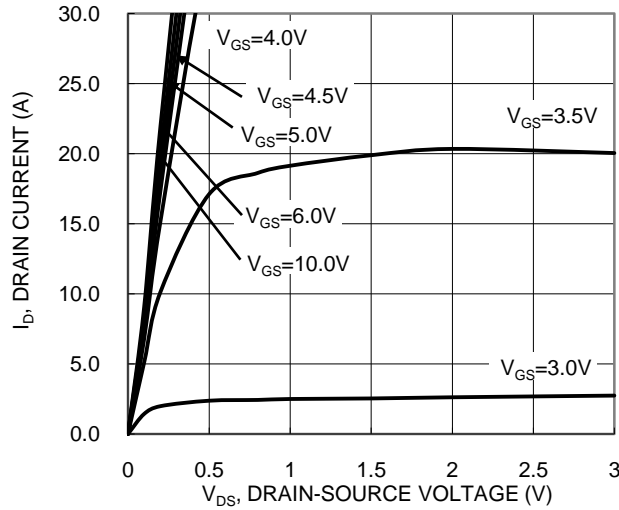


Figure 1. Typical Output Characteristic

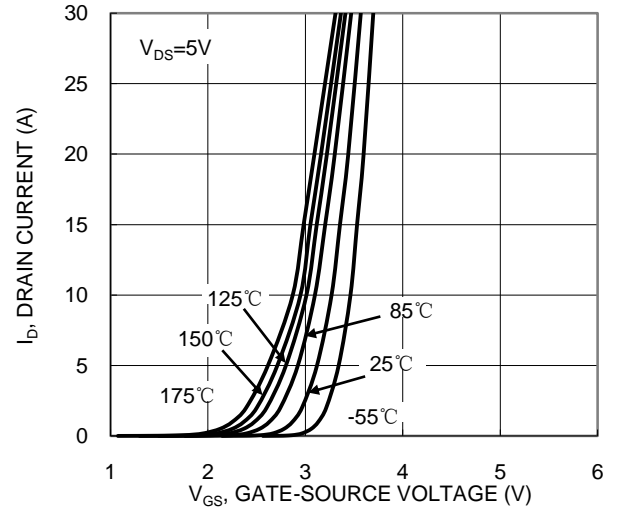


Figure 2. Typical Transfer Characteristic

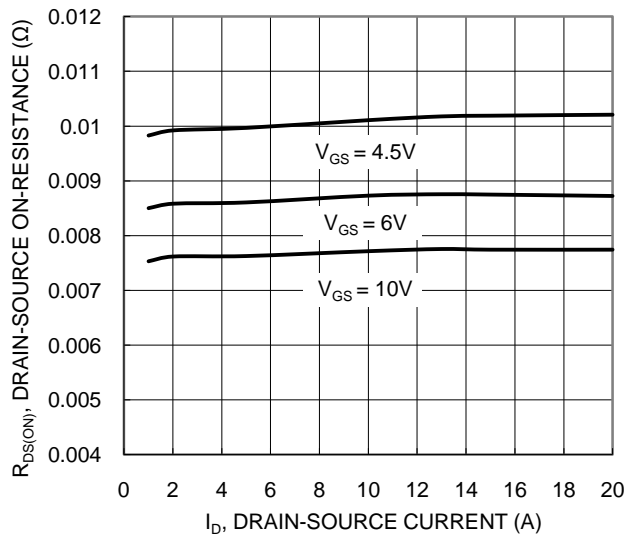


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

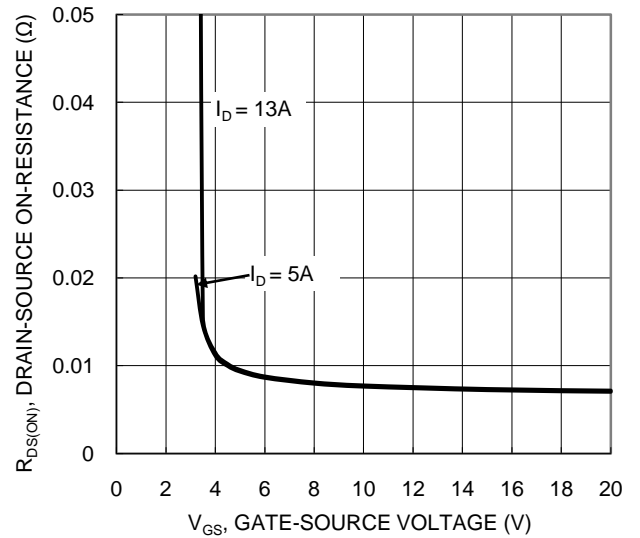


Figure 4. Typical Transfer Characteristic

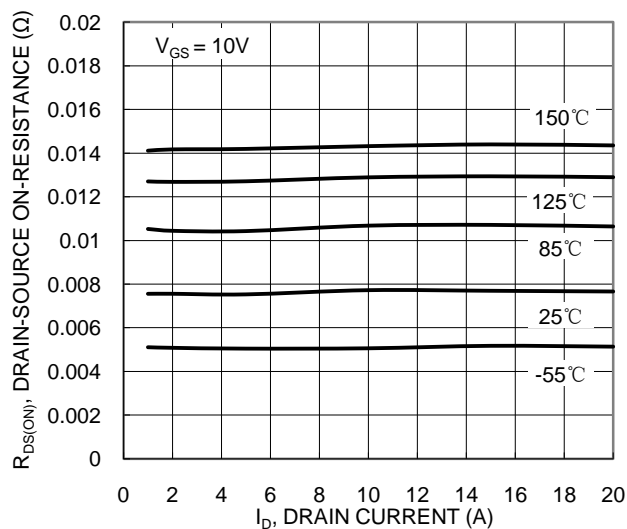


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

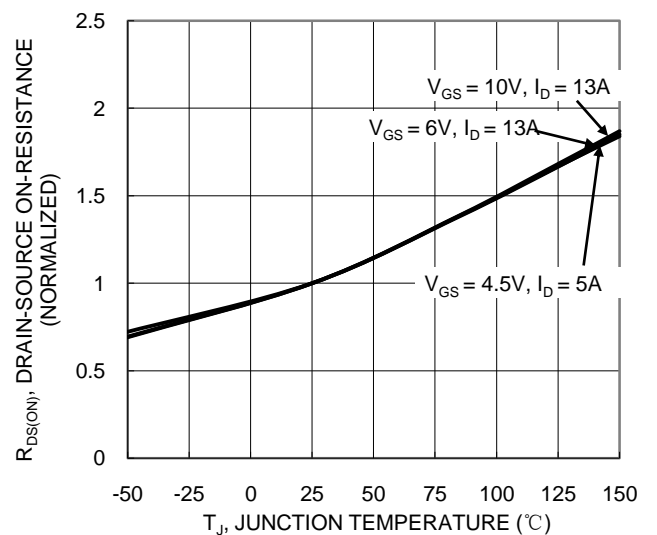
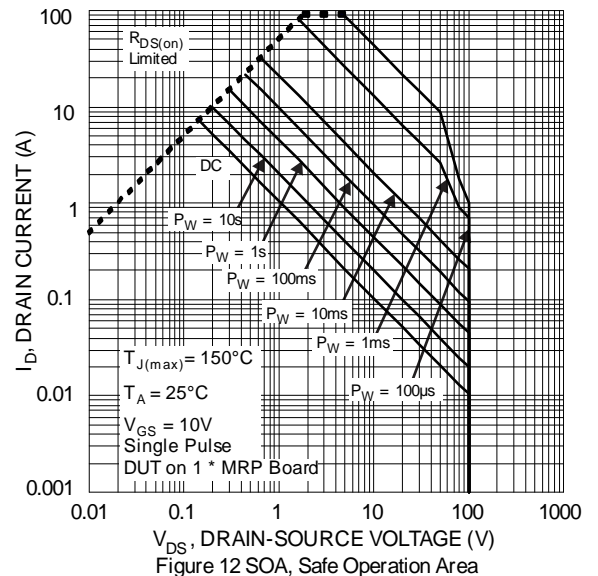
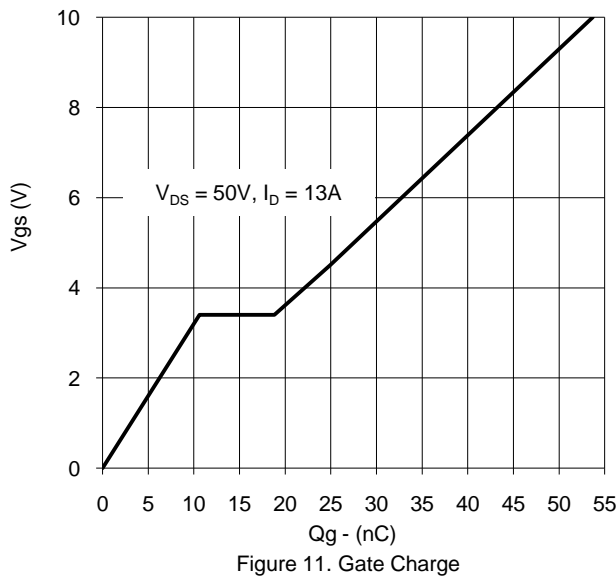
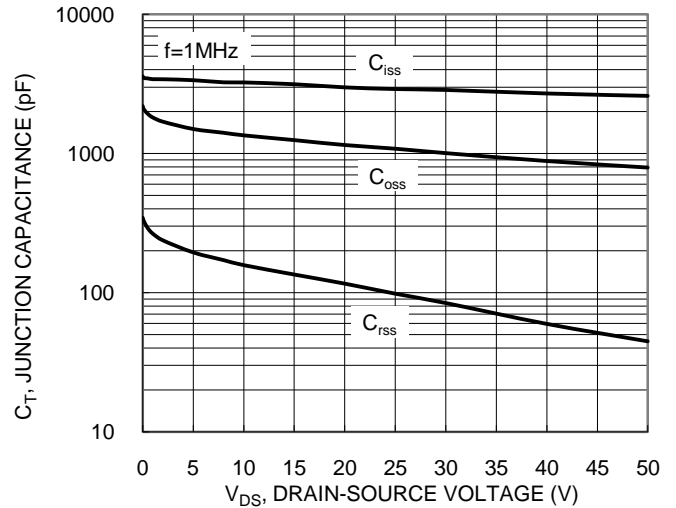
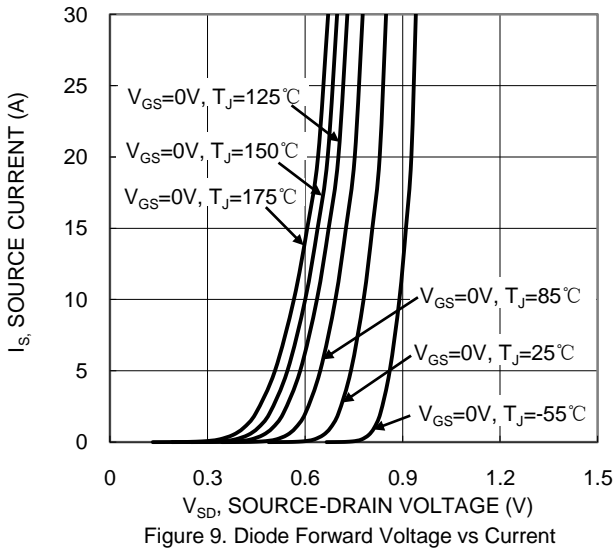
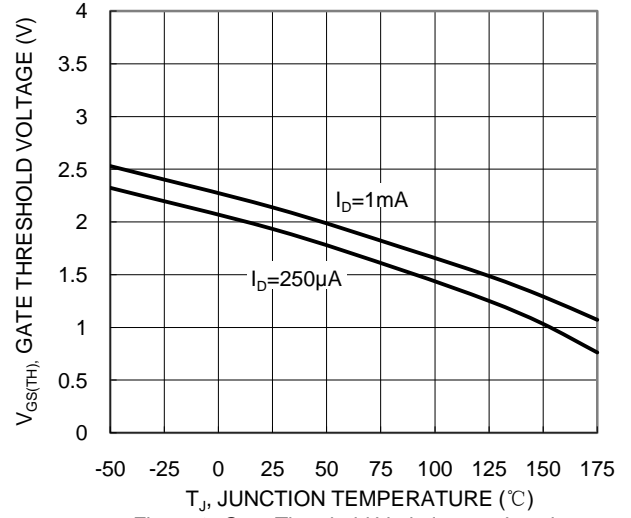
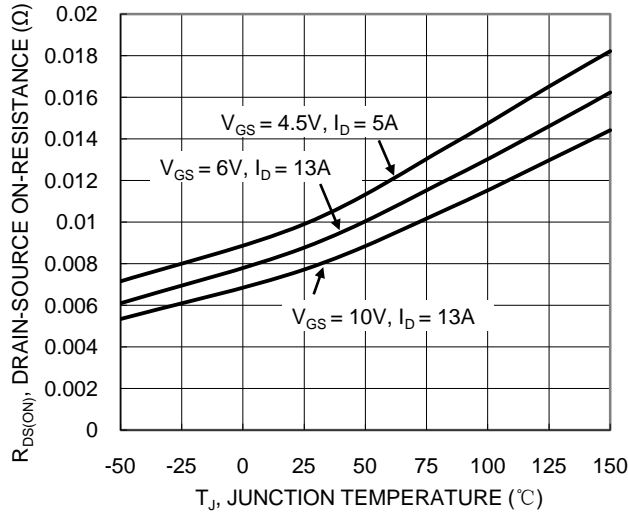
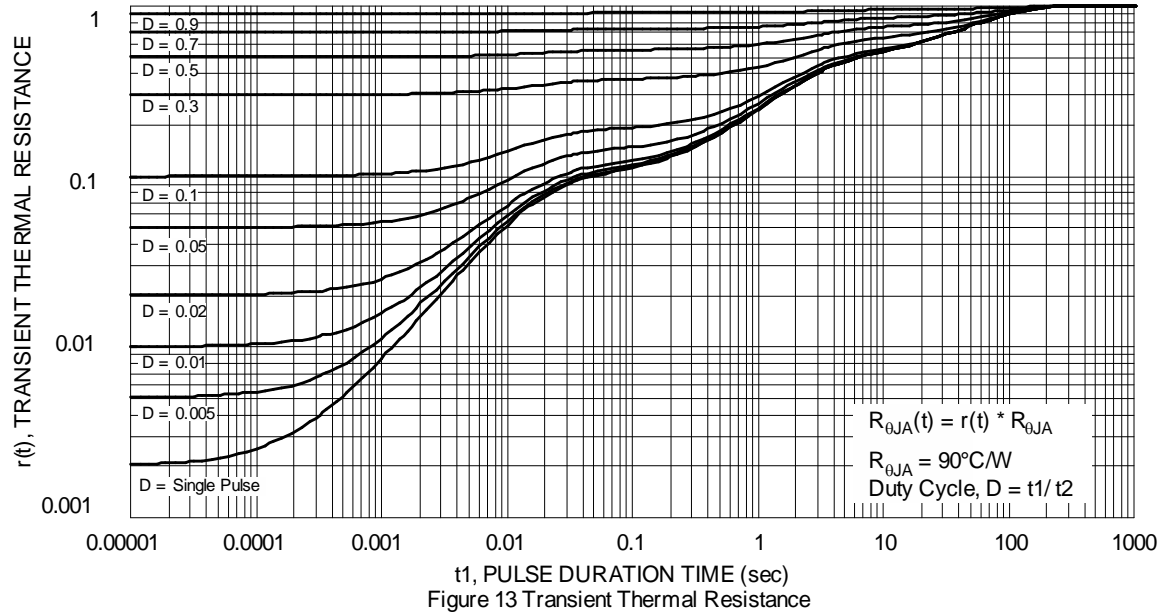


Figure 6. On-Resistance Variation with Temperature

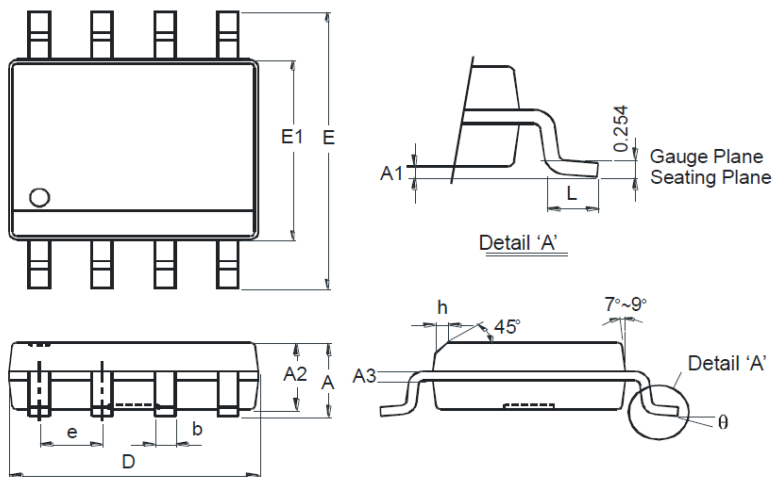




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SO-8

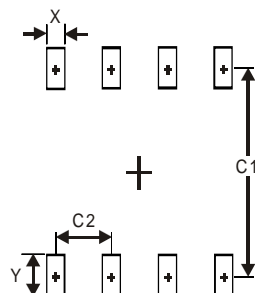


| SO-8 | | |
|----------------------|----------|------|
| Dim | Min | Max |
| A | - | 1.75 |
| A1 | 0.10 | 0.20 |
| A2 | 1.30 | 1.50 |
| A3 | 0.15 | 0.25 |
| b | 0.3 | 0.5 |
| D | 4.85 | 4.95 |
| E | 5.90 | 6.10 |
| E1 | 3.85 | 3.95 |
| e | 1.27 Typ | |
| h | - | 0.35 |
| L | 0.62 | 0.82 |
| θ | 0° | 8° |
| All Dimensions in mm | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.60 |
| Y | 1.55 |
| C1 | 5.4 |
| C2 | 1.27 |

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